

SEMICONDUCTOR TECHNICAL DATA

SMFB14

SCHOTTKY BARRIER TYPE DIODE

SWITCHING TYPE POWER SUPPLY APPLICATIONS.

FEATURES

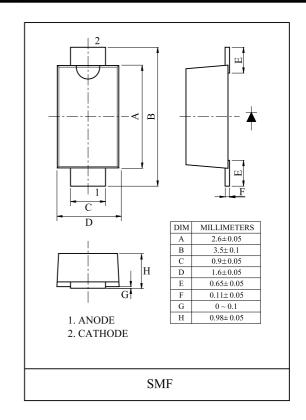
- \cdot Repetitive Peak Reverse Voltage : V_{RRM} =40V.
- \cdot Averge Output Rectitifed Current : $I_{O}\!\!=\!\!1.0A.$
- $\cdot \ Feak \ Forward \ Voltage: V_{FM}\!\!=\!\!0.50V(max.)$
- For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

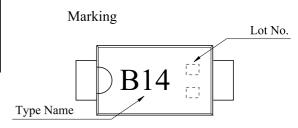
APPLICATION

- · Switching Power Supply.
- $\boldsymbol{\cdot}$ Reversed Battery Connection Protection.
- · DC/DC Converter.
- · Cellular Phones.

MAXIMUM RATING (Ta=25)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	V
Average Output Rectitifed Current	I _O	1	A
Peak One Cycle Surge Forward Current (Non-Repetitive 60Hz)	I _{FSM} 22		A
Junction Temperature	T _j	-40 125	
Storage Temperature Range	T_{stg}	-40 125	





ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V_{FM}	I _{FM} =1.0A	-	-	0.50	V
Repetitive Peak Reverse Current	I _{RRM}	V _{RRM} =Rated	-	-	1.0	mA
Thermal Resistance	R _{th(j-1)}	Junction to lead	-	-	20	
	R _{th(j-a)}	Junction to ambient	-	-	140	/W
		(on a grass-epoxy board)				

SMFB14

